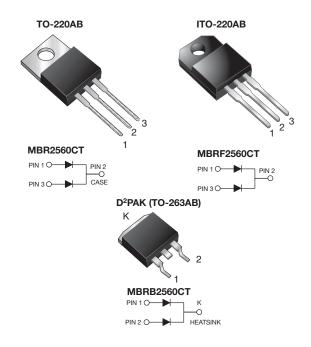
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MBR2560CT, MBRF2560CT, MBRB2560CT

Vishay General Semiconductor

Dual Common Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 12.5 A			
V _{RRM}	60 V			
I _{FSM}	150 A			
V _F	0.65 V at 15 A			
T _J max.	150 °C			
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB)			
Diode variation	Common cathode			

FEATURES

- Power pack
- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D²PAK (TO-263AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

PARAMETER	SYMBOL	MBR2560CT	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	60		
Working peak reverse voltage	V _{RWM}	60	V	
Maximum DC blocking voltage	V _{DC}	60		
Maximum average forward rectified current total device		25	— A	
at $T_C = 130 \text{ °C}$ per diode	IF(AV)	12.5		
Peak forward surge current 8.3 ms single half sine-wave superimposed rated load per diode	on I _{FSM}	150	A	
Peak repetitive reverse surge current per diode at $t_p = 2 \ \mu s$, 1 kHz	I _{RRM}	0.5		
Peak non-repetitive reverse energy (8/20 µs waveform) per diode	E _{RSM}	25	mJ	
Electrostatic discharge capacitor voltage human body model: C = 100 p R = 1.5 $k\Omega$	F, V _C	25	kV	
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs	
Operating junction temperature range	TJ	-65 to +150	°C	
Storage temperature range	T _{STG}	-65 to +175		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500	V	

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ELECTRICAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	MBR2560CT	UNIT		
Maximum instantaneous forward voltage per diode	I _F = 15 A	T _C = 25 °C	V _F ⁽¹⁾	0.75	v		
		T _C = 125 °C		0.65			
Maximum instantaneous reverse current at blocking voltage per diode		T _C = 25 °C	I _R ⁽¹⁾	1.0	mA		
		T _C = 125 °C		50			

Note

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	1.5	4.5	1.5	°C/W

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR2560CT-E3/45	1.85	45	50/tube	Tube	
ITO-220AB	MBRF2560CT-E3/45	1.99	45	50/tube	Tube	
TO-263AB	MBRB2560CT-E3/45	1.35	45	50/tube	Tube	
TO-263AB	MBRB2560CT-E3/81	1.35	81	800/reel	Tape and reel	



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RATINGS AND CHARACTERISTICS CURVES ($T_C = 25$ °C unless otherwise noted)

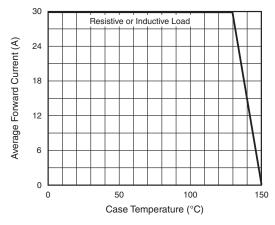


Fig. 1 - Forward Current Derating Curve

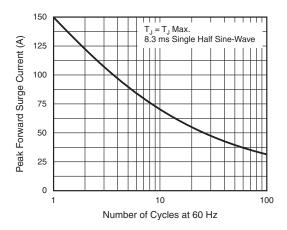


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

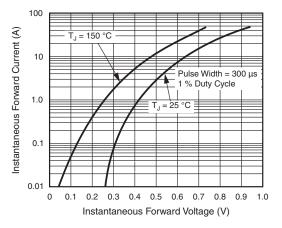


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

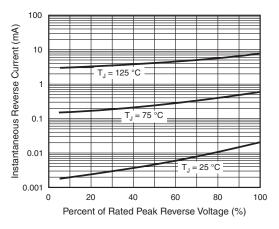


Fig. 4 - Typical Reverse Characteristics Per Diode

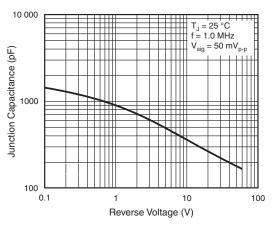


Fig. 5 - Typical Junction Capacitance Per Diode

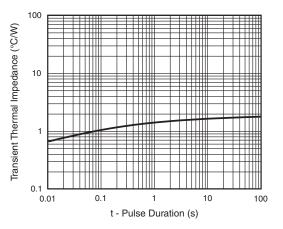


Fig. 6 - Typical Transient Thermal Impedance Per Diode

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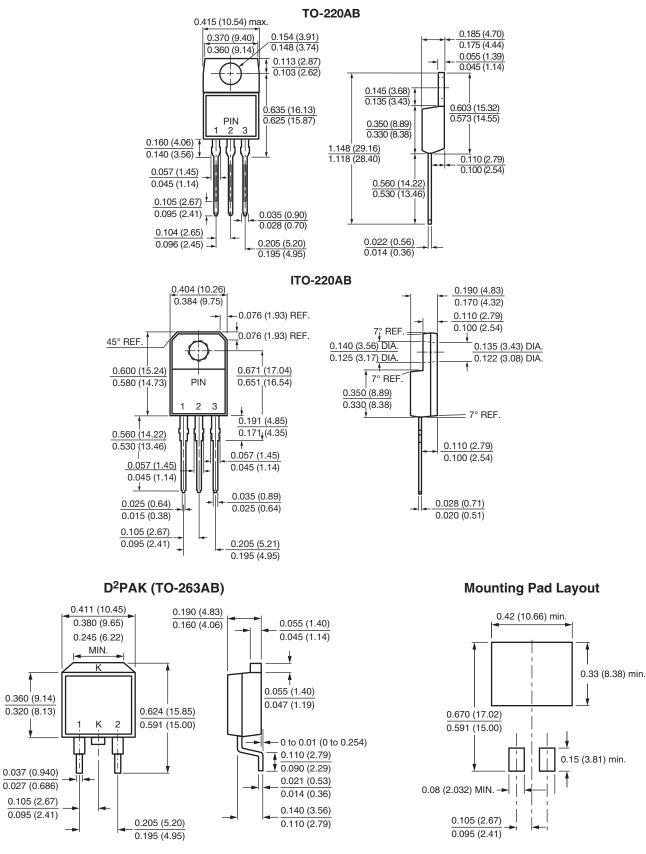
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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